

MOSFETs Silicon N-Channel MOS (DTMOSIV)

TK5A65W

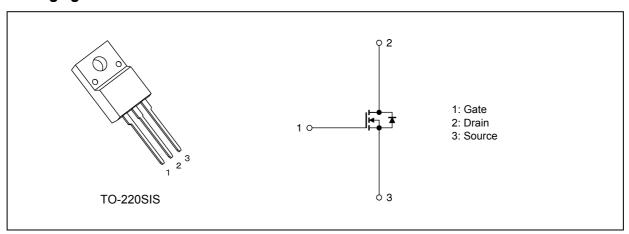
1. Applications

· Switching Voltage Regulators

2. Features

- (1) Low drain-source on-resistance: $R_{DS(ON)}$ = 1 $\Omega(typ.)$ by using Super Junction Structure: DTMOS
- (2) Easy to control Gate switching
- (3) Enhancement mode: $V_{th} = 2.5$ to 3.5 $V(V_{DS} = 10$ V, $I_D = 0.17$ mA)

3. Packaging and Internal Circuit



4. Absolute Maximum Ratings (Note) (Ta = 25 °C unless otherwise specified)

Characteristics	Symbol	Rating	Unit		
Drain-source voltage			V _{DSS}	650	V
Gate-source voltage			V _{GSS}	±30	
Drain current (DC)		(Note 1)	I _D	5.2	Α
Drain current (pulsed)		(Note 1)	I _{DP}	20.8	
Power dissipation	(T _c = 25 °C)		P _D	30	W
Single-pulse avalanche energy		(Note 2)	E _{AS}	70	mJ
Avalanche current			I _{AR}	1.3	Α
Reverse drain current (DC)		(Note 1)	I _{DR}	5.2	
Reverse drain current (pulsed)		(Note 1)	I _{DRP}	20.8]
Channel temperature			T _{ch}	150	°C
Storage temperature			T _{stg}	-55 to 150]
Isolation voltage (RMS)	(t = 1.0 s)		V _{ISO(RMS)}	2000	V
Mounting torque			TOR	0.6	N · m

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Start of commercial production



5. Thermal Characteristics

Characteristics		Max	Unit
Channel-to-case thermal resistance	R _{th(ch-c)}	4.17	°C/W
Channel-to-ambient thermal resistance	R _{th(ch-a)}	62.5	

Note 1: Ensure that the channel temperature does not exceed 150 °C.

Note 2: V_{DD} = 90 V, T_{ch} = 25 °C (initial), L = 73.6 mH, R_{G} = 25 Ω , I_{AR} = 1.3 A

Note: This transistor is sensitive to electrostatic discharge and should be handled with care.



6. Electrical Characteristics

6.1. Static Characteristics (T_a = 25 °C unless otherwise specified)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Gate leakage current	I _{GSS}	$V_{GS} = \pm 30 \text{ V}, V_{DS} = 0 \text{ V}$	_	_	±1	μΑ
Drain cut-off current	I _{DSS}	V _{DS} = 650 V, V _{GS} = 0 V	_	_	10	
Drain-source breakdown voltage	V _{(BR)DSS}	I _D = 10 mA, V _{GS} = 0 V	650	_	_	V
Gate threshold voltage	V _{th}	V _{DS} = 10 V, I _D = 0.17 mA	2.5	_	3.5	
Drain-source on-resistance	R _{DS(ON)}	V _{GS} = 10 V, I _D = 2.6 A	_	1	1.2	Ω

6.2. Dynamic Characteristics (T_a = 25 °C unless otherwise specified)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Input capacitance	C _{iss}	V _{DS} = 300 V, V _{GS} = 0 V, f = 1 MHz	_	380	_	pF
Reverse transfer capacitance	C _{rss}		_	1.5	_	
Output capacitance	C _{oss}		_	10	_	
Effective output capacitance	C _{o(er)}	V _{DS} = 0 to 400 V, V _{GS} = 0 V	_	16	_	
Gate resistance	r _g	V _{DS} = OPEN , f = 1 MHz	_	9	_	Ω
Switching time (rise time)	t _r	See Figure 6.2.1	_	17	_	ns
Switching time (turn-on time)	t _{on}		_	39	_	
Switching time (fall time)	t _f		_	5.5	_	
Switching time (turn-off time)	t _{off}		_	48	_	
MOSFET dv/dt ruggedness	dv/dt	V _{DD} = 0 to 400 V, I _D = 2.6 A	50			V/ns

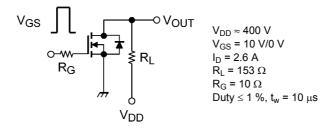


Fig. 6.2.1 Switching Time Test Circuit

6.3. Gate Charge Characteristics (T_a = 25 °C unless otherwise specified)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Total gate charge (gate-source plus gate-drain)	Q_g	$V_{DD} \approx 400 \text{ V}, V_{GS} = 10 \text{ V}, I_D = 5.2 \text{ A}$		10.5		nC
Gate-source charge 1	Q _{gs1}		_	2.7	_	
Gate-drain charge	Q_{gd}			4.6		

6.4. Source-Drain Characteristics (T_a = 25 °C unless otherwise specified)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Diode forward voltage	V_{DSF}	I _{DR} = 5.2 A, V _{GS} = 0 V	_	_	-1.7	V
Reverse recovery time	t _{rr}	I _{DR} = 2.6 A, V _{GS} = 0 V	_	175	_	ns
Reverse recovery charge	Q _{rr}	-dI _{DR} /dt = 100 A/μs	_	1.4	_	μС
Peak reverse recovery current	I _{rr}		_	13	_	Α
Diode dv/dt ruggedness	dv/dt	$I_{DR} = 2.6 \text{ A}, V_{GS} = 0 \text{ V}, V_{DD} = 400 \text{ V}$	15	_	_	V/ns



7. Marking (Note)

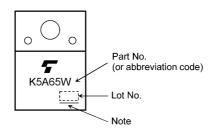


Fig. 7.1 Marking

Note: A line under a Lot No. identifies the indication of product Labels.

Not underlined: [[Pb]]/INCLUDES > MCV

Underlined: [[G]]/RoHS COMPATIBLE or [[G]]/RoHS [[Pb]]

 ${\it Please contact your TOSHIBA sales representative for details as to environmental matters such as the RoHS}$

compatibility of Product.

The RoHS is the Directive 2011/65/EU of the European Parliament and of the Council of 8 June 2011 on the

restriction of the use of certain hazardous substances in electrical and electronic equipment.

8. Characteristics Curves (Note)

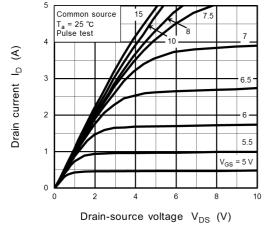
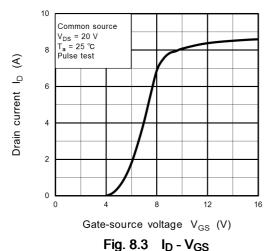


Fig. 8.1 I_D - V_{DS}



VGS = 0 V ID = 10 mA Pulse test Drain-source voltage V_{DSS} 650 600 550 -100 200 Ambient temperature T_a (°C)

Fig. 8.5 V_{DSS} - T_a

Common source

S

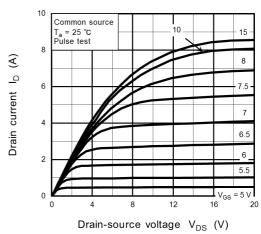
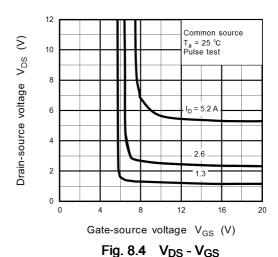


Fig. 8.2 I_D - V_{DS}



Drain-source on-resistance R_{DS(ON)} 0.1 $V_{GS} = 10 \text{ V}$ $T_a = 25 \text{ }^{\circ}\text{C}$ T_a = 25 °C Pulse test 0.01 Drain current I_D (A)

Fig. 8.6 R_{DS(ON)} - I_D

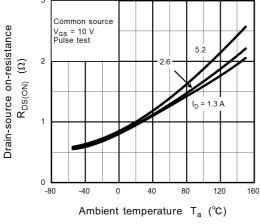
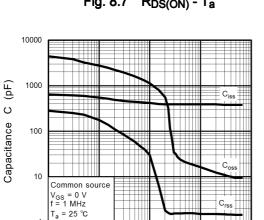


Fig. 8.7 R_{DS(ON)} - T_a



Drain-source voltage V_{DS} (V)

Fig. 8.9 C - V_{DS}

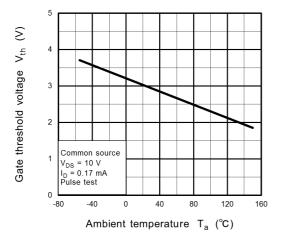


Fig. 8.11 V_{th} - T_a

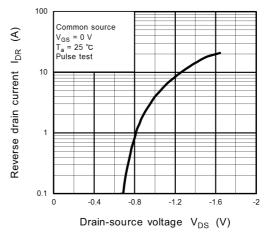


Fig. 8.8 IDR - VDS

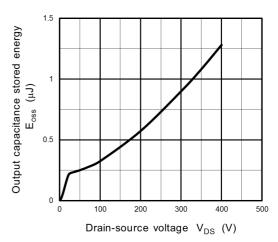


Fig. 8.10 Eoss - VDS

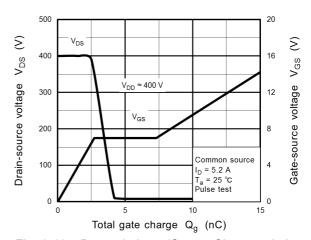


Fig. 8.12 Dynamic Input/Output Characteristics

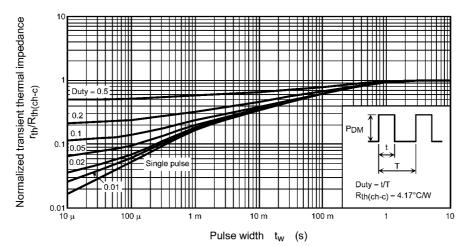


Fig. 8.13 r_{th} - t_w (Guaranteed Maximum)

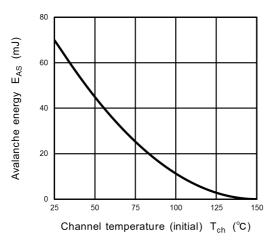


Fig. 8.14 E_{AS} - T_{ch} (Guaranteed Maximum)

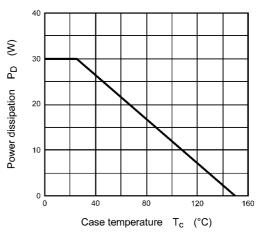


Fig. 8.15 P_D - T_c (Guaranteed Maximum)

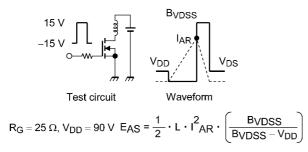


Fig. 8.16 Test Circuit/Waveform

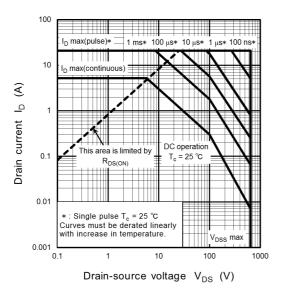


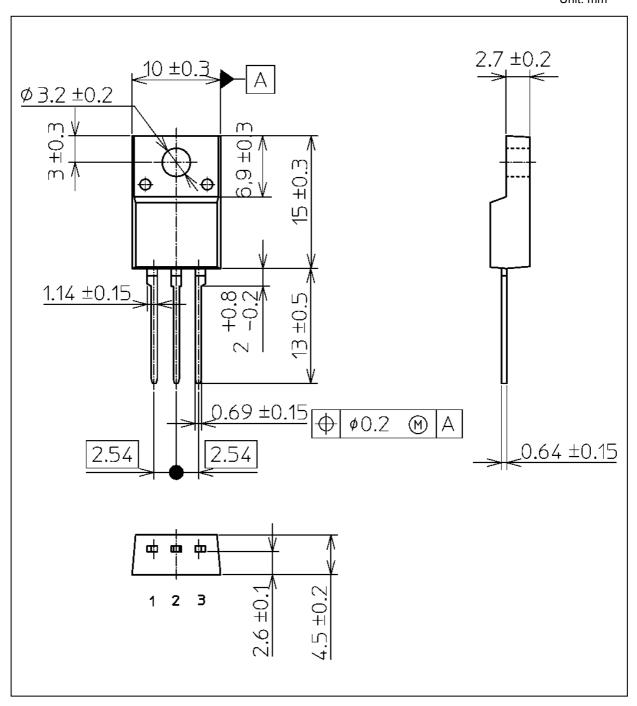
Fig. 8.17 Safe Operating Area (Guaranteed Maximum)

Note: The above characteristics curves are presented for reference only and not guaranteed by production test, unless otherwise noted.



Package Dimensions

Unit: mm



Weight: 1.7 g (typ.)

Package Name(s)	
JEITA: SC-67	
TOSHIBA: 2-10U1S	
Nickname: TO-220SIS	

Rev.4.0



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